NSN 5962-01-212-2692

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View Online at https://aerobasegroup.com/nsn/5962-01-212-2692

Body Length:
Between 0.370 inches and 0.380 inches
Body Width:
Between 0.370 inches and 0.380 inches
Body Height:
Between 0.070 inches and 0.085 inches
Maximum Power Dissipation Rating:
495.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Monolithic and schottky and low power and 3-state output
Inclosure Material:
Ceramic
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
16 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
75.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Ram
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
24 flat leads
Specification Data:
81349-mil-m-38510/231 government specification
Shelf Life:
N/a
Unit Of Measure:

Yes - demil/mli

Demilitarization:

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